

# SANYO Semiconductors DATA SHEET

## SBT150-10LS — Schottky Barrier Diode (Twin Type · Cathode Common) 100V, 15A Rectifier

## Applications

• High frequency rectification (switching regulators, converters, choppers).

## Features

- Tj=150°C.
- Low forward voltage (VF max=0.80V).
- Short reverse recovery time.
- Low switching noise.
- High reliability due to highly reliable planar structure.
- Micaless package facilitating mounting.

## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		100	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		105	V
Average Output Current	IO	50Hz resistive load, Sine wave Tc=43°C	15	А
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	80	А
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Reverse Voltage	VR	I <sub>R</sub> =2mA, Tj=25°C*	100			V
Forward Voltage	VF	IF=6A, Tj=25°C*			0.80	V
Reverse Current	IR	V <sub>R</sub> =50V, Tj=25°C*			0.2	mA
Interterminal Capacitance	С	VR=10V, Tj=25°C*		180		pF
Thermal Resistance	Rth(j-c)	Junction-Case : Smoothed DC			4.0	°C / W

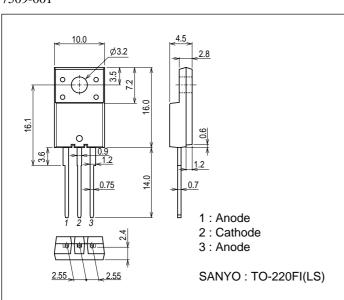
Note) \* : Value per element

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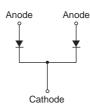
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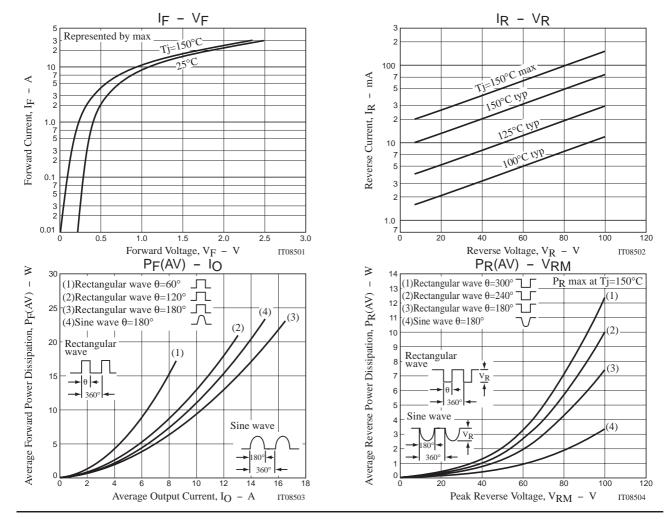
### Package Dimensions

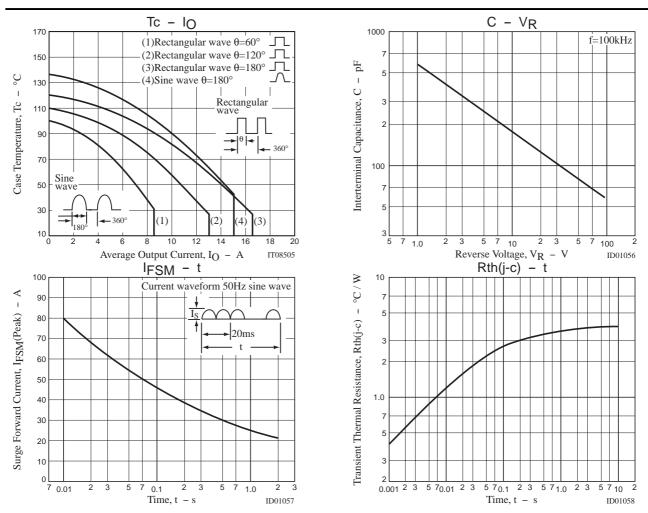
unit : mm 7509-001



## **Electrical Connection**







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